

SENSITRON
SEMICONDUCTOR

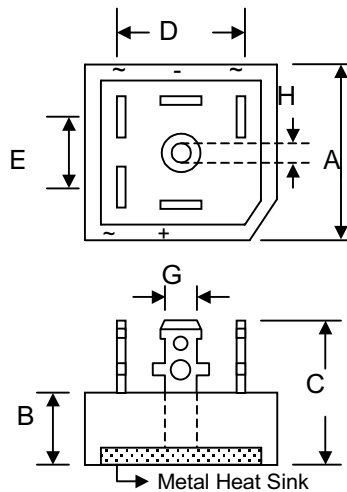
MT25, 35 -G SERIES
25, 35A THREE PHASE BRIDGE RECTIFIER

Data Sheet 1437, Rev. A

Green Products

Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- Ideal for Printed Circuit Boards
- UL Recognized File # E223064
- Green Products in Compliance with the RoHS Directive



MT				
Dim	Min	Max	Min	Max
A	28.40	28.70	1.118	1.130
B	10.97	11.23	0.432	0.442
C	22.86	23.86	0.9	0.939
D	—	25.30	—	0.996
E	16.00 Typical		0.630 Typical	
G	6.35 X 0.80		0.25 X 0.031	
H	5.10Ø	5.30Ø	0.201Ø	0.209Ø
	In mm		In inch	

Mechanical Data

- Case: Epoxy Case with Heat Sink Internally Mounted in the Bridge Encapsulation
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: As Marked on Body
- Weight: 20 grams (approx.)
- Mounting Position: Bolt Down on Heatsink With Silicone Thermal Compound Between Bridge and Mounting Surface for Maximum Heat Transfer Efficiency
- Mounting Torque: 20 in. lbs Max.
- Marking: Type Number

Maximum Ratings and Electrical Characteristics @ $T_A=25^{\circ}C$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Voltage Ratings

Characteristics	Symbol	-00-G	-01-G	-02-G	-04-G	-06-G	-08-G	-10-G	-12-G	-14-G	-16-G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	200	400	600	800	1000	1200	1400	1600	V
Peak Non-Repetitive Reverse Voltage	V_{RSM}	75	150	275	500	725	900	1100	1300	1500	1700	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	840	980	1120	V

Forward Conduction

Characteristic	Symbol	MT25	MT35	Unit
Average Rectified Output Current MT25 @ $T_C = 70^{\circ}C$, MT35 @ $T_C = 60^{\circ}C$	I_O	25	35	A
Non-Repetitive Peak Forward Surge Current (No Voltage Reapplied $t = 8.3ms$ at 60Hz) (No Voltage Reapplied $t = 10ms$ at 50Hz) (100% V_{RRM} Reapplied $t = 8.3ms$ at 60Hz) (100% V_{RRM} Reapplied $t = 8.3ms$ at 50Hz)	I_{FSM}	375 360 314 300	500 475 420 400	A

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I^2t Rating for Fusing (No-Voltage Reapplied $t = 8.3\text{ms}$ at 60Hz) (No-Voltage Reapplied $t = 10\text{ms}$ at 50Hz) (100% V_{RRM} Reapplied $t = 8.3\text{ms}$ at 60Hz) (100% V_{RRM} Reapplied $t = 10\text{ms}$ at 50Hz)	I^2t	580 635 410 450	1030 1130 730 800	A^2s
Forward Voltage (per element) @ $T_j = 25^\circ\text{C}$, @ $I_{FM} = 40A_{pk}$ per single junction	V_F	1.26	1.19	V
Peak Reverse Current (per leg) @ $T_j = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_j = 125^\circ\text{C}$	I_R		10 5.0	μA mA
RMS Isolation Voltage from Case to Lead	Viso		2500	V

Thermal Characteristics

Operating Temperature Range	T_j	-40 to +150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-40 to +150	$^\circ\text{C}$
Thermal Resistance Junction to Case at DC Operation per Bridge	$R_{\theta JC}$	1.42	1.16
Thermal Resistance Case to Heatsink Mounting Surface, Smooth, Flat and Greased	$R_{\theta CS}$	0.2	K/W

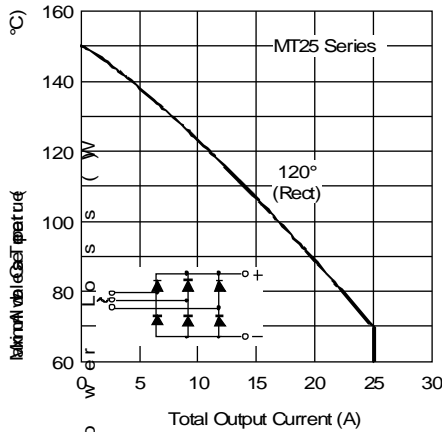


Fig. 1 - Current Ratings Characteristics

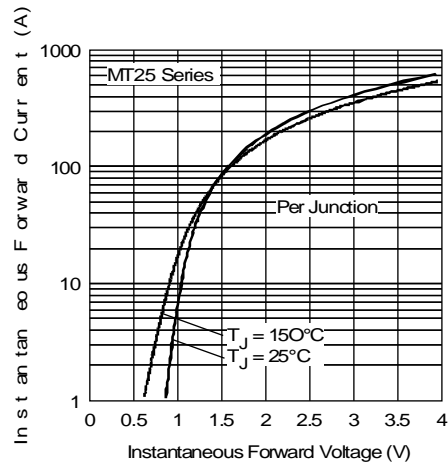


Fig. 2 - Forward Voltage Drop Characteristics

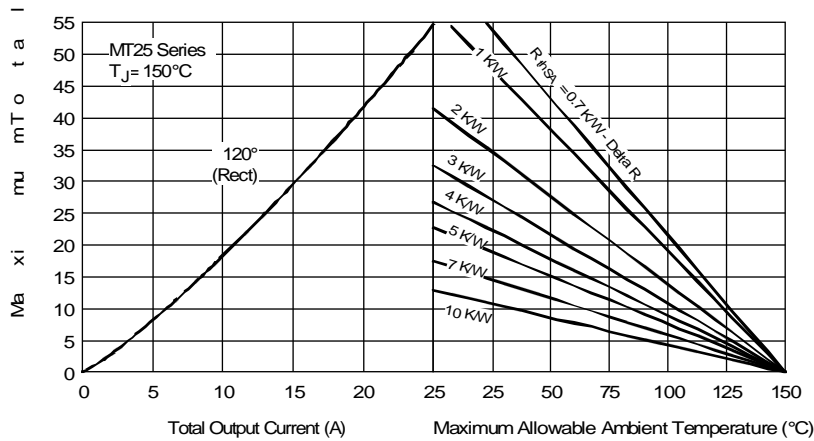


Fig. 3 - Total Power Loss Characteristics

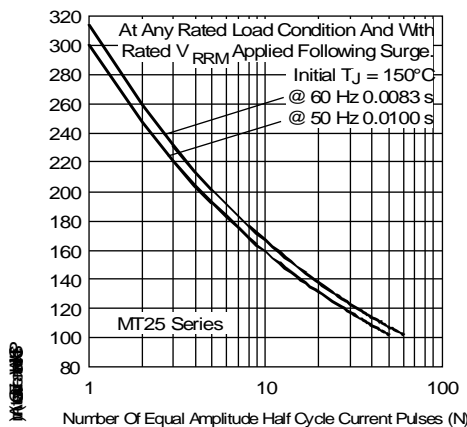


Fig. 4 - Maximum Non-Repetitive Surge Current

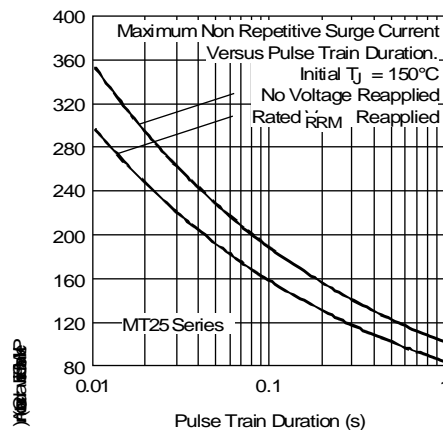


Fig. 5 - Maximum Non-Repetitive Surge Current

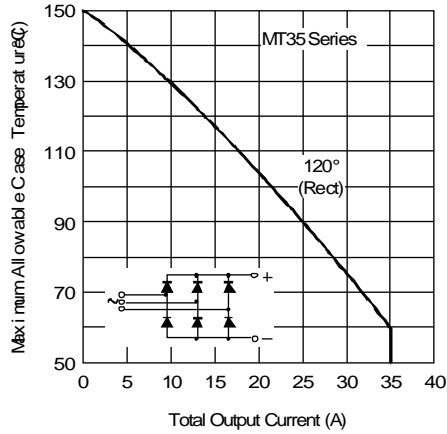


Fig. 6 - Current Ratings Characteristics

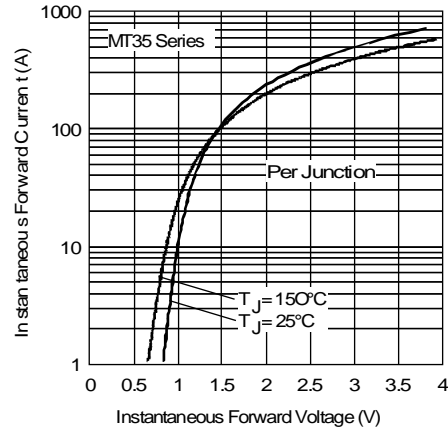


Fig. 7 - Forward Voltage Drop Characteristics

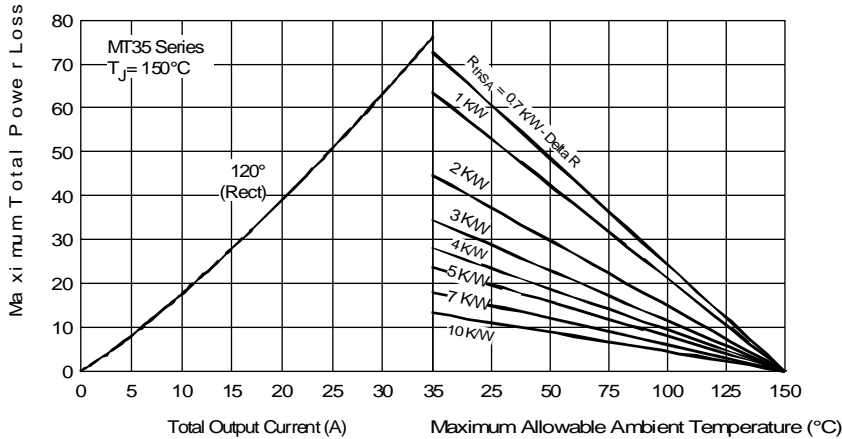


Fig. 8 - Total Power Loss Characteristics

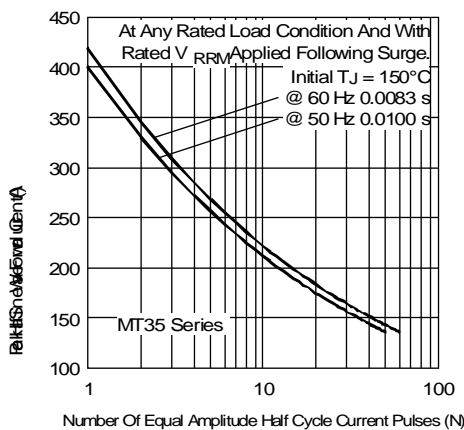


Fig. 9 - Maximum Non-Repetitive Surge Current

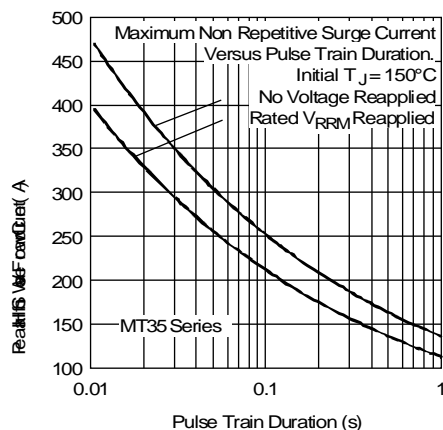


Fig. 10 - Maximum Non-Repetitive Surge Current

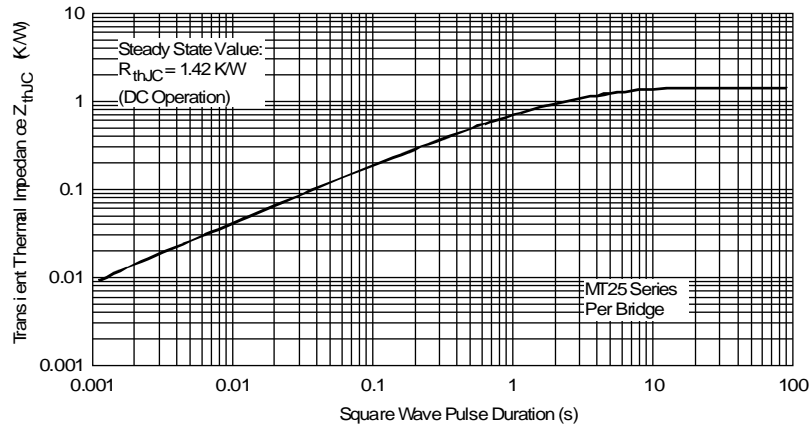


Fig. 11 - Thermal Impedance Z_{thJC} Characteristics

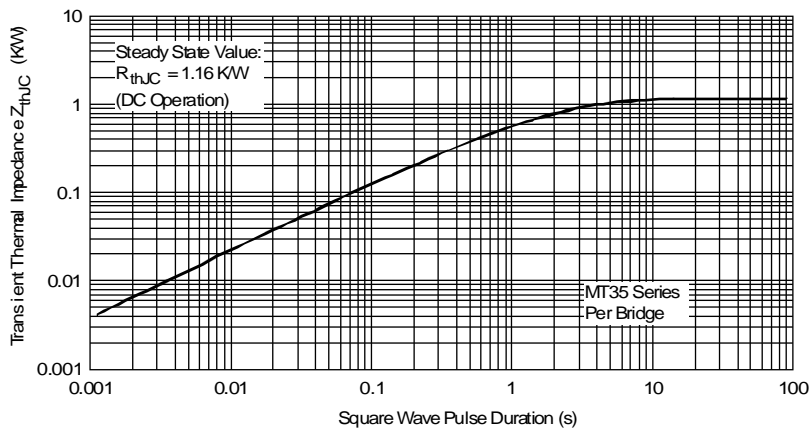


Fig. 12 - Thermal Impedance Z_{thJC} Characteristics

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